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Vishay Semiconductors

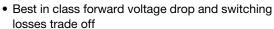
Hyperfast Rectifier, 30 A FRED Pt® G5

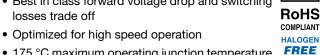


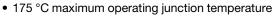
PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V_{R}	1200 V					
V _F at I _F at 125 °C	1.7 V					
t _{rr}	32 ns					
T _J max.	175 °C					
Package	TO-247AD 2L					
Circuit configuration	Single					

FEATURES

Hyperfast and optimized Q_{rr}







• Polyimide passivation

• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 115 °C, D = 0.50	30				
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	250	Α			
Repetitive peak forward current	I _{FRM}	T _C = 115 °C, D = 0.50, f = 20 kHz	60				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	$I_R = 100 \mu A$	1200	1	=			
Forward voltage	V _F	I _F = 30 A	-	1.9	2.3	V		
		I _F = 30 A, T _J = 125 °C	-	1.7	-			
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	50			
neverse leakage current		$T_J = 125 ^{\circ}\text{C}$, $V_R = V_R$ rated	-	-	500	μA		
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, dI_F/dt = 100$	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		32	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	113	-	ns	
		T _J = 125 °C		-	175	-		
Poak rocoveny current	1	T _J = 25 °C	$I_F = 20 \text{ A}$ $dI_F/dt = 600 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	17	-	Α	
Peak recovery current	IRRM	T _J = 125 °C		-	26	-		
Doverse receivery charge	0	T _J = 25 °C		-	850	-	nC	
Reverse recovery charge	Q_{rr}	T _J = 125 °C		-	2150	-		
Reverse recovery time		T _J = 25 °C	I _F = 30 A dI _F /dt = 1000 A/μs V _R = 800 V	-	85	-	- ns	
neverse recovery time	t _{rr}	T _J = 125 °C		-	132	-		
Dools was a seems assument		T _J = 25 °C		-	30	-	А	
Peak recovery current	IRRM	T _J = 125 °C		-	43	-		
Reverse recovery charge	0	T _J = 25 °C			1350	-	nC	
	Q _{rr}	T _J = 125 °C		-	3215	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction-to-case	R_{thJC}		-	-	0.8	°C/W	
Weight			-	5.5	-	g	
			-	0.2	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Marking device		Case style: TO-247AD 2L	E5PH3012L				

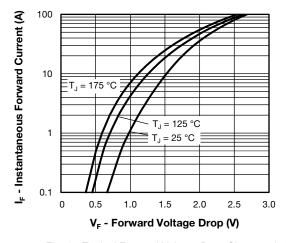


Fig. 1 - Typical Forward Voltage Drop Characteristics

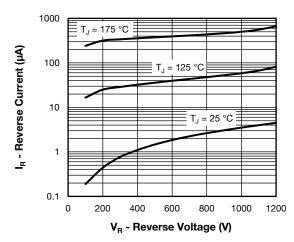


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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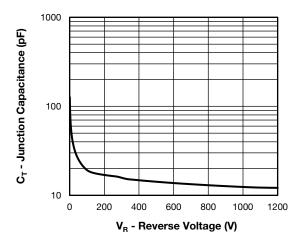


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

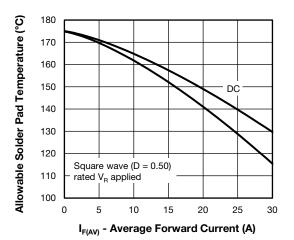


Fig. 4 - Maximum Allowable Case Temperature vs.

Average Forward Current

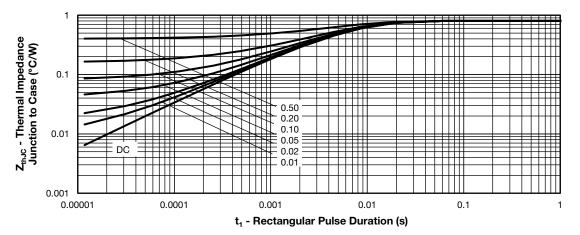


Fig. 5 - Thermal Impedance Z_{thJC} Characteristics

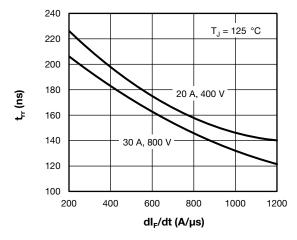


Fig. 6 - Typical Reverse Recovery Time vs. $dI_{\mbox{\scriptsize F}}/dt$

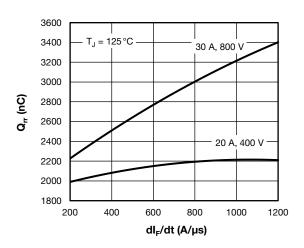


Fig. 7 - Typical Stored Charge vs. dl_F/dt

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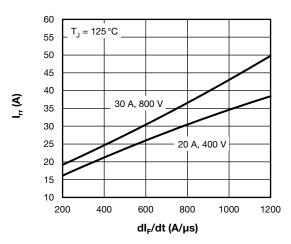


Fig. 8 - Typical Recovery Current vs. dl_F/dt

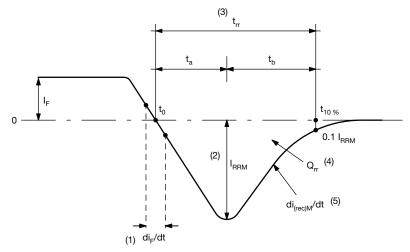


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

(1) di_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}

 $^{(4)}$ $\,Q_{rr}$ - area under curve defined by t_0 and $t_{10}\,\%$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

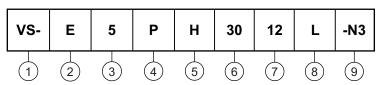


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ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 E = single diode
- 3 5 = Fred generation 5
- 4 Package:
 - P = TO-247 package
- 5 H = hyperfast recovery
- 6 Current rating (30 = 30 A)
- 7 Voltage rating (12 = 1200 V)
- Package: L = long lead (TO-247AD)
- 9 Environmental digit:
 - -N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5PH3012L-N3	25	500	Antistatic plastic tube				

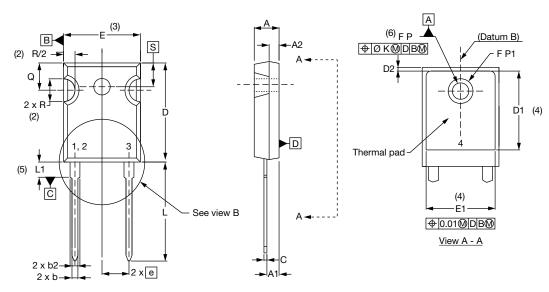
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95536				
Part marking information	www.vishay.com/doc?95648				
Spice model	www.vishay.com/doc?96685				

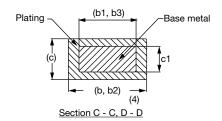


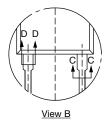
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TO-247AD 2L

DIMENSIONS in millimeters and inches







SYMBOL	MILLIN	MILLIMETERS		INCHES		
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.65	5.31	0.183	0.209		
A1	2.21	2.59	0.087	0.102		
A2	1.50	2.49	0.059	0.098		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.34	0.065	0.092		
С	0.38	0.89	0.015	0.035		
c1	0.38	0.84	0.015	0.033		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	
D2	0.51	1.35	0.020	0.053		

SYMBOL	MILLIM	IETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	'BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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ACGRB207-HF CLH03(TE16L,Q) ACGRC307-HF ACEFC304-HF NTE6356 NTE6359 NTE6002 NTE6023 NTE6039 NTE6077

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